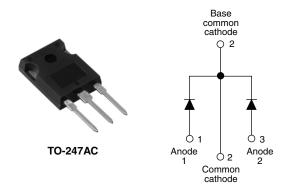


### Vishay High Power Products

### **HEXFRED®** Ultrafast Soft Recovery Diode, 2 x 15 A



PRODUCT SUMMARY					
$V_{R}$	600 V				
V <sub>F</sub> at 15 A at 25 °C	1.7 V				
I <sub>F(AV)</sub>	2 x 15 A				
t <sub>rr</sub> (typical)	19 ns				
T <sub>J</sub> (maximum)	150 °C				
Q <sub>rr</sub> (typical)	80 nC				
dl <sub>(rec)M</sub> /dt (typical)	160 A/μs				
I <sub>RRM</sub> (typical)	4.0 A				

#### **FEATURES**

- Ultrafast recovery
- · Ultrasoft recovery
- Very low I<sub>RRM</sub>
- Very low Q<sub>rr</sub>
- · Specified at operating conditions
- · Designed and qualified for industrial level

#### **BENEFITS**

- · Reduced RFI and EMI
- · Reduced power loss in diode and switching transistor
- Higher frequency operation
- · Reduced snubbing
- · Reduced parts count

#### DESCRIPTION

HFA30PA60C is a state of the art center tap ultrafast recovery diode. Employing the latest in epitaxial construction and advanced processing techniques it features a superb combination of characteristics which result in performance which is unsurpassed by any rectifier previously available. With basic ratings of 600 V and 15 A per leg continuous current, the HFA30PA60C is especially well suited for use as the companion diode for IGBTs and MOSFETs. In addition to ultrafast recovery time, the HEXFRED® product line features extremely low values of peak recovery current (I<sub>RRM</sub>) and does not exhibit any tendency to "snap-off" during the t<sub>b</sub> portion of recovery. The HEXFRED features combine to offer designers a rectifier with lower noise and significantly lower switching losses in both the diode and the switching transistor. These HEXFRED advantages can help to significantly reduce snubbing, component count and heatsink sizes. The HEXFRED HFA30PA60C is ideally suited for applications in power supplies and power conversion systems (such as inverters), motor drives, and many other similar applications where high speed, high efficiency is needed.

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Cathode to anode voltage	$V_{R}$		600	V	
Maximum continuous forward current per leg	- IF	T <sub>C</sub> = 100 °C	15		
per device			30	Α	
Single pulse forward current	I <sub>FSM</sub>		150	A	
Maximum repetitive forward current	I <sub>FRM</sub>		60		
Maximum nauga discipation	P <sub>D</sub>	T <sub>C</sub> = 25 °C	74	W	
Maximum power dissipation		T <sub>C</sub> = 100 °C	29		
Operating junction and storage temperature range	T <sub>J</sub> , T <sub>Stg</sub>		- 55 to + 150	°C	

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### HFA30PA60C

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# HEXFRED® Ultrafast Soft Recovery Diode, 2 x 15 A

<b>ELECTRICAL SPECIFICATIONS PER LEG</b> (T <sub>J</sub> = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNITS
Cathode to anode breakdown voltage	V <sub>BR</sub>	Ι <sub>R</sub> = 100 μΑ		600	-	-	
		I <sub>F</sub> = 15 A		-	1.3	1.7	V
Maximum forward voltage V <sub>FM</sub>	I <sub>F</sub> = 30 A	See fig. 1	-	1.5	2.0		
		I <sub>F</sub> = 15 A, T <sub>J</sub> = 125 °C		-	1.2	1.6	
Maximum reverse		$V_R = V_R$ rated	See fig. 2	-	1.0	10	
leakage current	I <sub>RM</sub>	$T_J = 125 ^{\circ}\text{C},  V_R = 0.8  \text{x}  V_R  \text{rated}$	See lig. 2	-	400	1000	μΑ
Junction capacitance	C <sub>T</sub>	V <sub>R</sub> = 200 V	See fig. 3	=	25	50	pF
Series inductance	L <sub>S</sub>	Measured lead to lead 5 mm from package body		=	12	-	nH

<b>DYNAMIC RECOVERY CHARACTERISTICS PER LEG</b> (T <sub>J</sub> = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNITS
D	t <sub>rr</sub>	$I_F = 1.0 \text{ A}, dI_F/dt = 200 \text{ A/}\mu\text{s}, V_R = 30 \text{ V}$		-	19	-	
Reverse recovery time See fig. 5, 10	t <sub>rr1</sub>	T <sub>J</sub> = 25 °C	_	-	42	60	ns
000 lig. 0, 10	t <sub>rr2</sub>	T <sub>J</sub> = 125 °C		-	70	120	
Peak recovery current	eak recovery current $I_{RRM1}$ $T_J = 25  ^{\circ}C$	-	4.0	6.0	Α		
See fig. 6	I <sub>RRM2</sub>	T <sub>J</sub> = 125 °C	I <sub>F</sub> = 15 A	-	6.5	10	^
Reverse recovery charge	Q <sub>rr1</sub>	T <sub>J</sub> = 25 °C	$dI_F/dt = 200 \text{ A/}\mu\text{s}$ $V_R = 200 \text{ V}$	-	80	180	nC
See fig. 7	Q <sub>rr2</sub>	T <sub>J</sub> = 125 °C		-	220	600	110
Peak rate of fall of recovery current during t <sub>b</sub>	GI(rec)M/GIT   1J = 25 G	-	250	-	A/μs		
See fig. 8	dI <sub>(rec)M</sub> /dt2	T <sub>J</sub> = 125 °C		-	160	-	Α, μο

THERMAL - MECHANICAL SPECIFICATIONS PER LEG						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Lead temperature	T <sub>lead</sub>	0.063" from case (1.6 mm) for 10 s	-	-	300	°C
Junction to case, single leg conduction	В		-	-	1.7	
Junction to case, both legs conducting	R <sub>thJC</sub>		-	-	0.85	KAM
Thermal resistance, junction to ambient	R <sub>thJA</sub>	Typical socket mount	-	-	40	K/W
Thermal resistance, case to heatsink	R <sub>thCS</sub>	Mounting surface, flat, smooth and greased	-	0.25	-	
Maight			-	6.0	-	g
Weight			-	0.21	-	OZ.
Mounting torque			6.0 (5.0)	-	12 (10)	kgf · cm (lbf · in)
Marking device		Case style TO-247AC (JEDEC)	HFA30PA60C			

www.vishay.com

For technical questions, contact: diodestech@vishay.com



# HEXFRED® Vishay High Power Products Ultrafast Soft Recovery Diode, 2 x 15 A

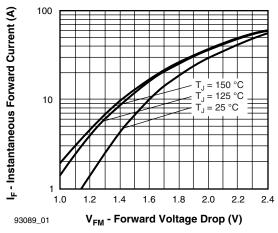


Fig. 1 - Maximum Forward Voltage Drop vs. Instantaneous Forward Current (Per Leg)

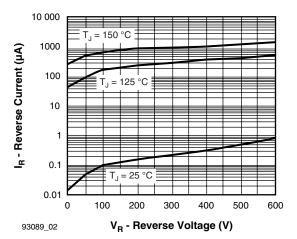


Fig. 2 - Typical Reverse Current vs. Reverse Voltage (Per Leg)

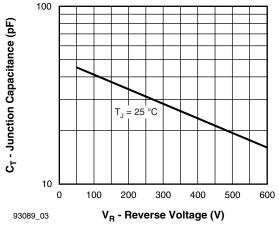


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)

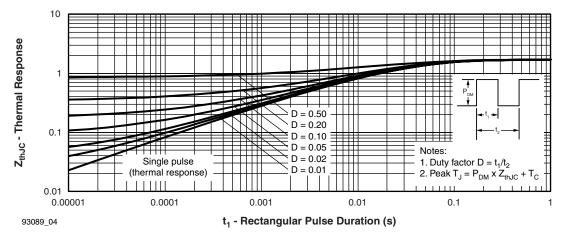


Fig. 4 - Maximum Thermal Impedance Z<sub>thJC</sub> Characteristics (Per Leg)

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# HEXFRED® Ultrafast Soft Recovery Diode, 2 x 15 A



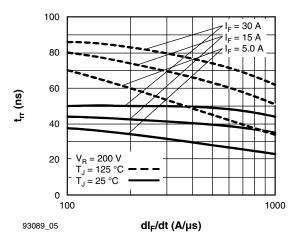


Fig. 5 - Typical Reverse Recovery Time vs.  $dI_F/dt$  (Per Leg)

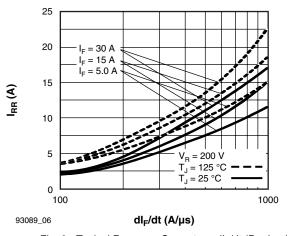


Fig. 6 - Typical Recovery Current vs.  $dI_F/dt$  (Per Leg)

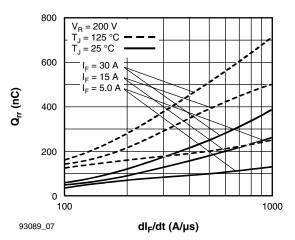


Fig. 7 - Typical Stored Charge vs.  $dI_F/dt$  (Per Leg)

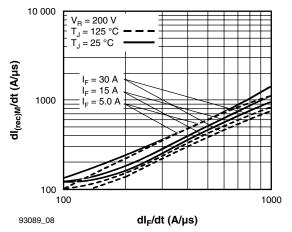


Fig. 8 - Typical  $dI_{(rec)M}/dt$  vs.  $dI_F/dt$  (Per Leg)



# HEXFRED® Vishay High Power Products Ultrafast Soft Recovery Diode, 2 x 15 A

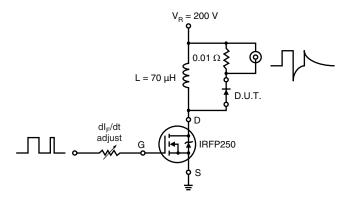
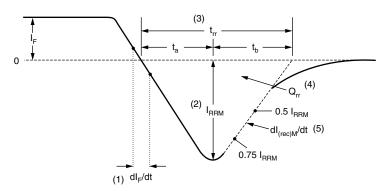


Fig. 9 - Reverse Recovery Parameter Test Circuit



- (1) dl<sub>F</sub>/dt rate of change of current through zero crossing
- (2)  $I_{RRM}$  peak reverse recovery current
- (3) t<sub>rr</sub> reverse recovery time measured from zero crossing point of negative going I<sub>F</sub> to point where a line passing through 0.75 I<sub>RRM</sub> and 0.50 I<sub>RRM</sub> extrapolated to zero current.
- (4)  $\mathbf{Q}_{\rm rr}$  area under curve defined by  $\mathbf{t}_{\rm rr}$  and  $\mathbf{I}_{\rm RRM}$

$$Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$$

(5) dI<sub>(rec)M</sub>/dt - peak rate of change of current during t<sub>b</sub> portion of t<sub>rr</sub>

Fig. 10 - Reverse Recovery Waveform and Definitions

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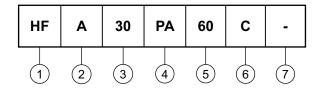
### HEXFRED®





#### **ORDERING INFORMATION TABLE**

**Device code** 



- 1 HEXFRED® family
- Process designator: A = Subs. electron irradiated

B = Subs. platinum

- 3 Current rating (30 = 30 A)
- Package outline (PA = TO-247, 3 pins)
- 5 Voltage rating (60 = 600 V)
- 6 Configuration (C = Center tap common cathode)
- 7 • None = Standard production
  - PbF = Lead (Pb)-free

LINKS TO RELATED DOCUMENTS				
Dimensions	www.vishay.com/doc?95223			
Part marking information	www.vishay.com/doc?95226			
SPICE model	www.vishay.com/doc?95182			

www.vishay.com

For technical questions, contact: diodestech@vishay.com



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